

BU505

High Voltage NPN Multiepitaxial Fast-Switching Transistor

Features

- HIGH VOLTAGE CAPABILITY
- VERY HIGH SWITCHING SPEED
- HIGH RUGGEDNESS

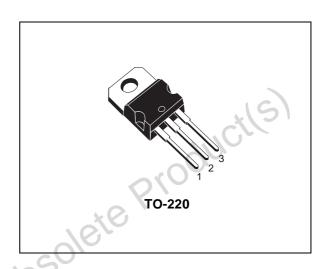
Applications

- ELECTRONIC BALLASTS FOR FLUORESCENT LIGHTING
- SWITCH MODE POWER SUPPLIES

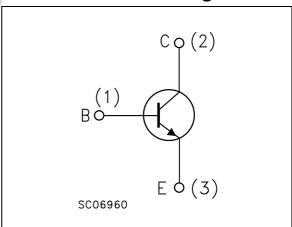
Description

The BU505 is a High Voltage NPN fastswitching transistor designed to be used in lighting application, like electronic ballast for fluorescent lamps.

It's characteristics make also ideal for power supplies.



Internal Schematic Diagram



Order Codes

Part Number	Marking	Package	Packing
BU505	BU505	TO-220	TUBE

rev.4

August 2005 1/10

1 Absolute Maximum Ratings

Table 1. Absolute Maximum Rating

Symbol	Parameter	Value	Unit
V _{CES}	Collector-Emitter Voltage (V _{BE} = 0)	1500	V
V _{CEO}	Collector-Emitter Voltage (I _B = 0)	700	V
I _C	Collector Current	2.5	Α
I _{CM}	Collector Peak Current (t _P < 5ms)	4	Α
I _B	Base Current	1	Α
I _{BM}	Base Peak Current (t _P < 5ms)	2	Α
P _{TOT}	Total dissipation at T _C = 25°C	75	W
T _{STG}	Storage Temperature -65 to 150		°C
TJ	Max. Operating Junction Temperature	150	°C

Table 2. Thermal Data

Symbol	Parameter	16/0	Value	Unit
R _{thJ-case}	Thermal Resistance Junction-Case	Max	1.67	°C/W
	oroduct(s)	202		l
Obsoli	ate Y			

BU505 2 Electrical Characteristics

2 Electrical Characteristics

Table 3. Electrical Characteristics ($T_{CASE} = 25^{\circ}C$; unless otherwise specified)

Symbol	Parameter	Test (Conditions	Min.	Тур.	Max.	Unit
I _{CES}	Collector Cut-off Current	V _{CE} = 1500V				0.15	mA
	$(V_{BE} = 0)$	V _{CE} = 1500V	$T_C = 125$ °C			1	mA
I _{EBO}	Emitter Cut-off Current (I _C = 0)	V _{EB} = 5V				1	mA
V _{CEO(sus)}	Collector-Emitter	I _C = 10mA		700			V
Note: 1	Sustaining Voltage (I _B = 0)	L = 25mH				.10	6
V _{CE(sat)} Note: 1	Collector-Emitter Saturation Voltage	I _C = 2A	I _B = 0.9A		AL.	C1.	V
V _{BE(sat)} Note: 1	Base-Emitter Saturation Voltage	I _C = 2A	I _B = 0.9A	01	5	1.3	V
I _{s/b}	Second Breakdown Current	V _{CE} = 120V	t = 220μs	2			Α
	INDUCTIVE LOAD	I _C = 2A	V _{clamp} = 250V				
t _s	Storage Time	$I_{B1} = 0.7A$	$V_{be(off)} = -5A$		2		μs
t _f	Fall Time	$R_{bb} = 0$	L = 200 μH		350		ns

Note: 1 Pulsed duration = 300 μs, duty cycle ≤1.5%.



2 Electrical Characteristics BU505

2.1 Typical Characteristics

Figure 1. Safe Operating Area

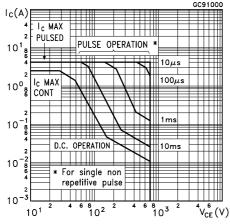


Figure 2. Derating Curve

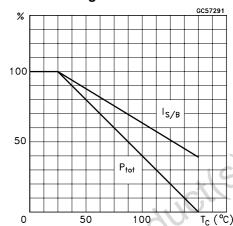


Figure 3. DC Current Gain

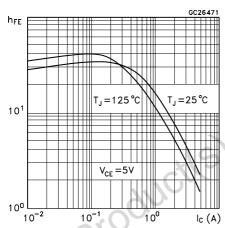


Figure 4. Collector Emitter Saturation Voltage

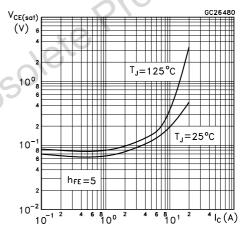


Figure 5. Base Emitter Storage Time

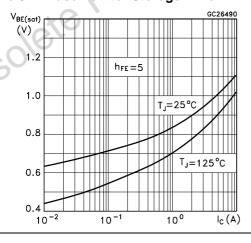
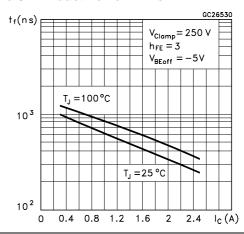


Figure 6. Inductive Fall Time



BU505 2 Electrical Characteristics

Inductive Storage Time Figure 7.

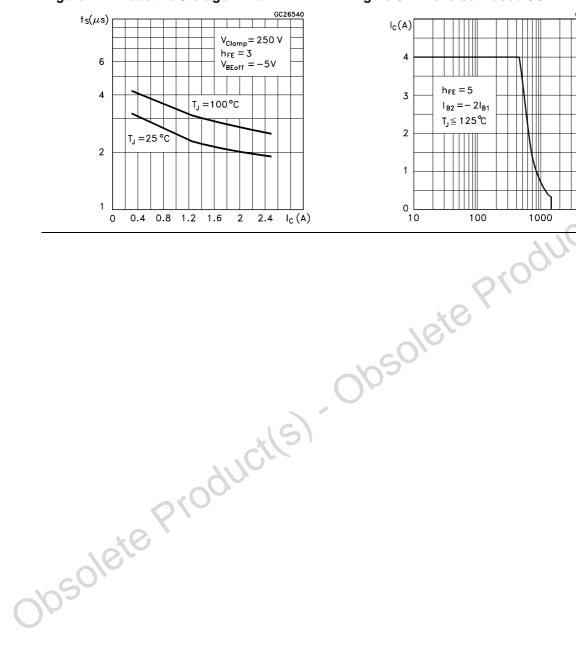
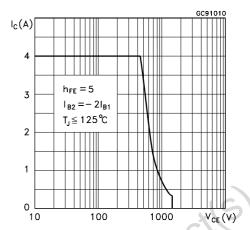


Figure 8. **Reverse Biased SOA**

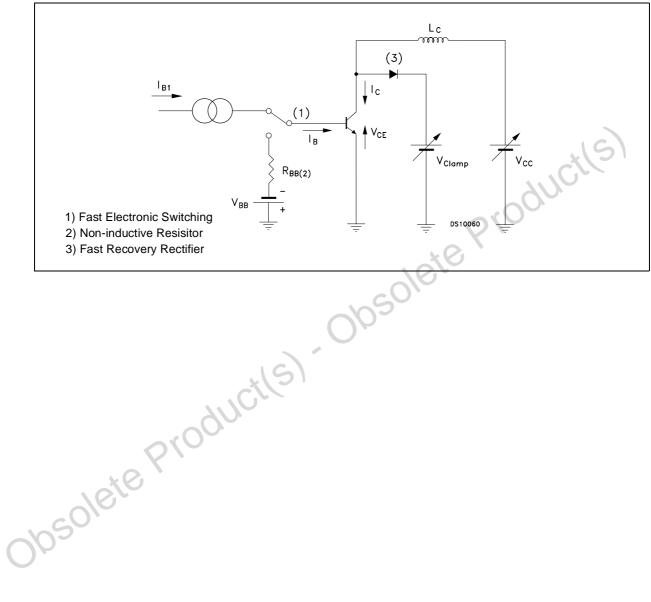


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3 Test Circuits

3 Test Circuits

Figure 9. Inductive Load Switching Test Circuit



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4 Package Mechanical Data

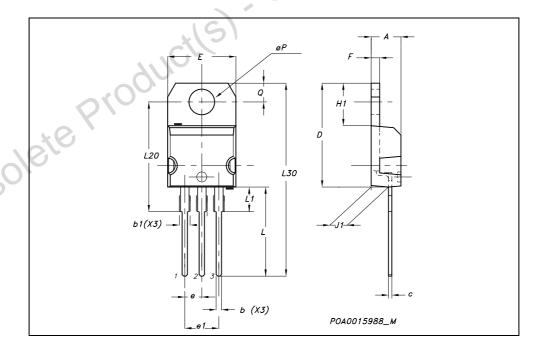
In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a Lead-free second level interconnect . The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com

Obsolete Product(s). Obsolete Product(s)

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TO-220 MECHANICAL DATA

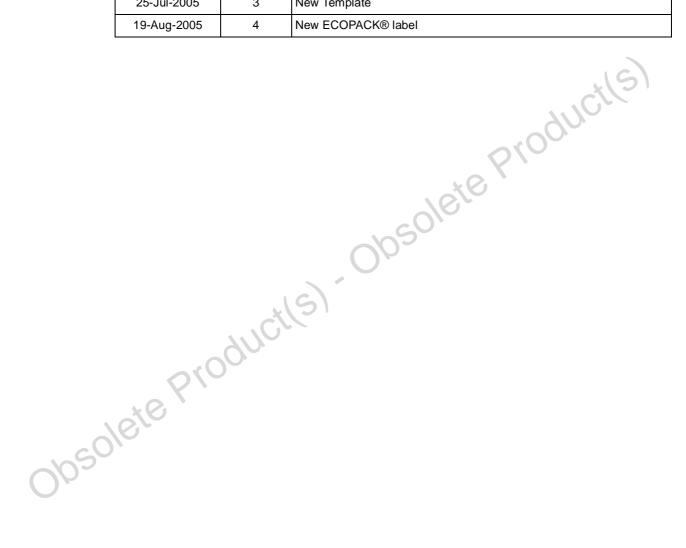
DIM.		mm.			inch	
DIM.	MIN.	TYP	MAX.	MIN.	TYP.	MAX.
Α	4.40		4.60	0.173		0.181
b	0.61		0.88	0.024		0.034
b1	1.15		1.70	0.045		0.066
С	0.49		0.70	0.019		0.027
D	15.25		15.75	0.60		0.620
Е	10		10.40	0.393		0.409
е	2.40		2.70	0.094		0.106
e1	4.95		5.15	0.194		0.202
F	1.23		1.32	0.048		0.052
H1	6.20		6.60	0.244	(0.256
J1	2.40		2.72	0.094		0.107
L	13		14	0.511		0.551
L1	3.50		3.93	0.137	2	0.154
L20		16.40		101	0.645	
L30		28.90			1.137	
øΡ	3.75		3.85	0.147		0.151
Q	2.65		2.95	0.104		0.116



BU505 5 Revision History

5 Revision History

Date	Revision	Changes
05-Sep-2001	1	Initial release.
06-Jul-2005	2	Some value change in <i>Table 3</i> .
25-Jul-2005	3	New Template
19-Aug-2005	4	New ECOPACK® label



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5 Revision History



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